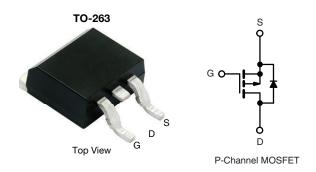


www.vishay.com

Vishay Siliconix

Automotive P-Channel 40 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY					
V _{DS} (V)	-40				
$R_{DS(on)}(\Omega)$ at $V_{GS} = -10 \text{ V}$	0.00300				
$R_{DS(on)}(\Omega)$ at $V_{GS} = -4.5 \text{ V}$	0.00380				
I _D (A)	-120				
Configuration	Single				
Package	TO-263				

FEATURES

- TrenchFET® power MOSFET
- · Package with low thermal resistance
- 100 % R_q and UIS tested
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



FREE

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V _{DS}	-40	.,	
Gate-Source Voltage	V _{GS}	± 20	V		
Continuous Drain Current ^a	T _C = 25 °C	I _D	-120		
	T _C = 125 °C		-120		
Continuous Source Current (Diode conduc	Is	-120	Α		
Pulsed Drain Current ^b		I _{DM}		-300	
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	-60		
Single Pulse Avalanche Energy	L = 0.1 MH	E _{AS}	180	mJ	
Maximum Power Dissipation b	T _C = 25 °C	Б	375	W	
waximum rower dissipation 5	T _C = 125 °C	P_{D}	125] vv	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER	SYMBOL	LIMIT	UNIT		
Junction-to-Ambient PCB	mount c R _{thJA}	40	90 AM		
Junction-to-Case (Drain)	R _{thJC}	0.4	°C/W		

Notes

- a. Package limited.
- b. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- c. When mounted on 1" square PCB (FR4 material).

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PARAMETER	SYMBOL	TES	T CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$		-40	-	-	V
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	V _{DS} = V _{GS} , I _D = -250 μA		-2.0	-2.5	\ \
Gate-Source Leakage	I _{GSS}	V _{DS} =	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-	± 100	nA
		V _{GS} = 0 V	V _{DS} = -40 V	-	-	-1	
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V	V _{DS} = -40 V, T _J = 125 °C	-	-	-50	μΑ
		V _{GS} = 0 V	V _{DS} = -40 V, T _J = 175 °C	-	-	-450	
On-State Drain Current ^a	I _{D(on)}	V _{GS} = -10 V	V _{DS} ≤ -5 V	-100	-	-	Α
		V _{GS} = -10 V	I _D = -30 A	-	0.00250	0.00300	
Drain-Source On-State Resistance a	ь	V _{GS} = -10 V	I _D = -30 A, T _J = 125 °C	-	-	0.00440	Ω
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} = -10 V	I _D = -30 A, T _J = 175 °C	-	-	0.00520	
		V _{GS} = -4.5 V	I _D = -25 A	-	0.00316	0.00380	
Forward Transconductance b	9 _{fs}	V _{DS} =	V _{DS} = -15 V, I _D = -25 A		123	-	S
Dynamic ^b							
Input Capacitance	C _{iss}		V _{DS} = -25 V, f = 1 MHz	-	30 000	39 000	pF
Output Capacitance	C _{oss}	$V_{GS} = 0 V$		-	1850	2500	
Reverse Transfer Capacitance	C _{rss}	1			1550	2100	
Total Gate Charge ^c	Qg			-	527	800	
Gate-Source Charge c	Q _{gs}	V _{GS} = -10 V	$V_{GS} = -10 \text{ V}$ $V_{DS} = -20 \text{ V}, I_D = -80 \text{ A}$		89	-	nC
Gate-Drain Charge ^c	Q _{gd}				100	-	
Gate Resistance	Rg	f = 1 MHz		1	2.26	3.5	Ω
Turn-On Delay Time ^c	t _{d(on)}			-	21	35	
Rise Time ^c	t _r	V _{DD} =	-20 V, R _L = 0.3 Ω	-	30	50	- ns
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong -80 \text{ A},$	V_{GEN} = -10 V, R_g = 1 Ω	-	250	400	
Fall Time ^c	t _f			-	165	300	
Source-Drain Diode Ratings and Cha	racteristics b						
Pulsed Current ^a	I _{SM}			-	-	-300	Α
Forward Voltage	V _{SD}	I _F =	-80 A, V _{GS} = 0 V	-	-0.85	-1.5	V
Body diode reverse recovery time	t _{rr}	I _F = -50 A, di/dt = 100 A/μs		-	70	140	ns
Body diode reverse recovery charge	Q _{rr}			-	134	270	nC
Reverse recovery fall time	t _a			-	43	-	
Reverse recovery rise time	t _b			-	35	-	ns
	†	1			1	1	

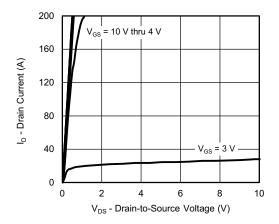
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

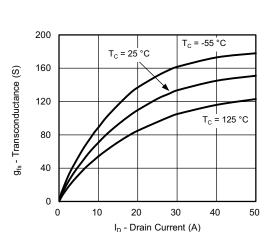
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



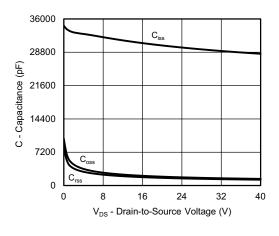
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



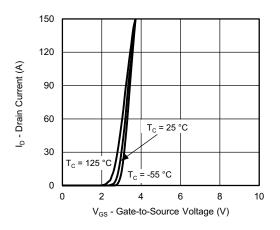
Output Characteristics



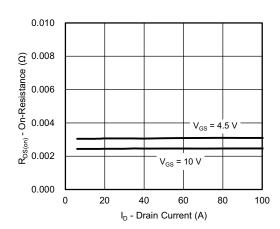
Transconductance



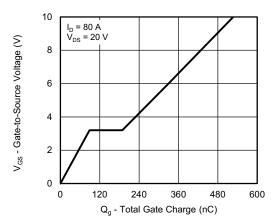
Capacitance



Transfer Characteristics



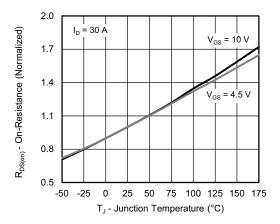
On-Resistance vs. Drain Current



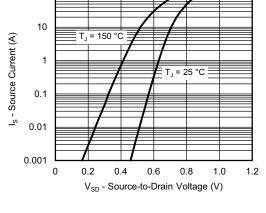
Gate Charge



TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

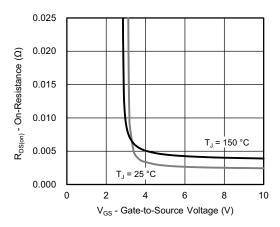


On-Resistance vs. Junction Temperature

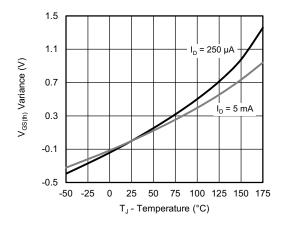


100

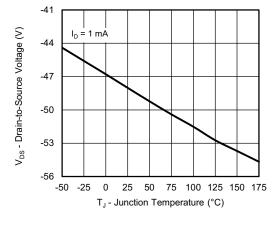
Source Drain Diode Forward Voltage



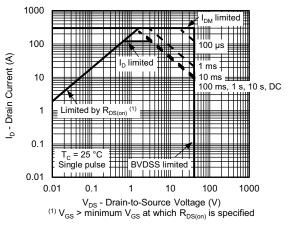
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



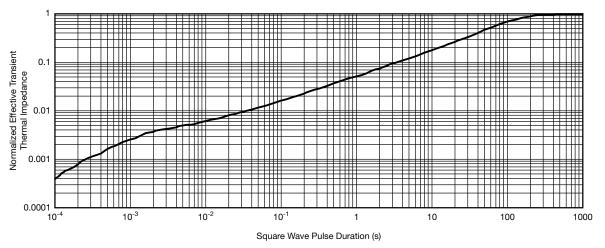
Drain Source Breakdown vs. Junction Temperature



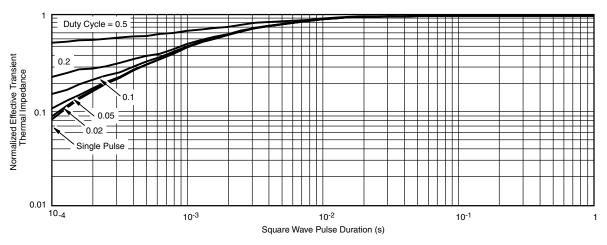
Safe Operating Area



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

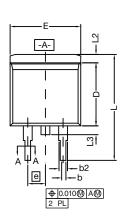
Note

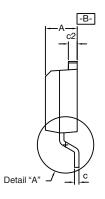
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction to Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction to Case (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

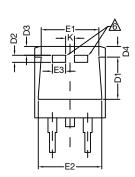
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TO-263 (D²PAK): 3-LEAD

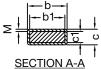








DETAIL A (ROTATED 90°)



= 1	b	<u>.</u>
$\geq \frac{1}{1}$	ਹ //////	
c		\Box

- 1. Plane B includes maximum features of heat sink tab and plastic.
- 2. No more than 25 % of L1 can fall above seating plane by max. 8 mils.
- 3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB. Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.

6 This feature is for thick lead.

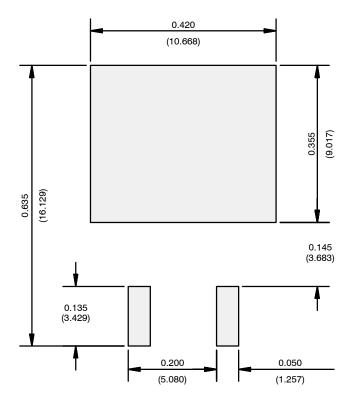
		INC	HES	MILLIMETERS		
DIM.		MIN.	MAX.	MIN.	MAX.	
Α		0.160	0.190	4.064	4.826	
	b	0.020	0.039	0.508	0.990	
	b1	0.020	0.035 0.508		0.889	
	b2	0.045	0.055	1.143	1.397	
c*	Thin lead	0.013	0.018	0.330	0.457	
	Thick lead	0.023	0.028	0.584	0.711	
c1	Thin lead	0.013	0.017	0.330	0.431	
CI	Thick lead	0.023	0.027	0.584	0.685	
	c2	0.045	0.055	1.143	1.397	
	D	0.340	0.380	8.636	9.652	
	D1	0.220	0.240	5.588	6.096	
	D2	0.038	0.042	0.965	1.067	
	D3	0.045	0.055	1.143	1.397	
	D4	0.044	0.052	1.118	1.321	
	Е	0.380	0.410	9.652	10.414	
	E1	0.245	-	6.223	-	
	E2	0.355	0.375	9.017	9.525	
	E3	0.072	0.078	1.829	1.981	
	е	0.100	BSC	2.54 BSC		
K		0.045	0.055	1.143	1.397	
	L	0.575	0.625	14.605	15.875	
L1		0.090	0.110	2.286	2.794	
	L2	0.040	0.055	1.016	1.397	
L3		0.050	0.070	1.270	1.778	
L4		0.010	BSC	0.254 BSC		
	М	- 0.002		-	0.050	
ECN: T13-0707-Rev. K, 30-Sep-13						

DWG: 5843





RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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